

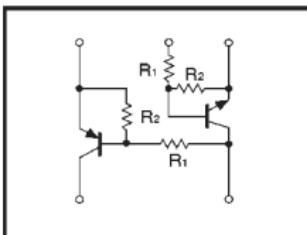
Power management (dual digital transistors)

FMC6A

●Features

- Both the DTA115E and DTC115E chips in a SMT package.

●Circuit diagram



●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	V _I (off)	—	—	0.5	V	V _{CC} =5/-5V , I _O =100/-100 μA
	V _I (on)	3	—	—		V _O =0.3/-0.3V , I _O =1/-1mA
Output voltage	V _O (on)	—	0.1	0.3	V	I _C =5/-5mA , I _E =0.25/-0.25mA
Input current	I _I	—	—	0.15	mA	V _I =5/-5V
Output current	I _O (off)	—	—	0.5	μA	V _{CC} =50/-50V
DC current gain	G _I	82	—	—	—	I _O =5/-5mA , V _O =5/-5V
Transition frequency	f _T	—	250	—	MHz	V _{CE} =10V/-10V , I _E =-5mA/5mA , f=100MHz *
Input resistance	R _I	70	100	130	kΩ	—
Resistance ratio	R ₂ /R ₁	0.8	1	1.2	—	—

* Transition frequency of mounted transistor. PNP type negative symbols have been omitted.

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Supply voltage	V _{CC}	50	V
		40	V
		-10	
Output current	I _C	100	mA
	I _O	20	mA
Power dissipation	P _D	300 (TOTAL)	mW
Storage temperature	T _{STG}	-55~+150	°C

PNP type negative symbols have been omitted.

●Package, marking, and packaging specifications

Part No.	FMC6A
Package	SMT5
Marking	C6
Code	T148
Basic ordering unit (pieces)	3000